

CPH3303

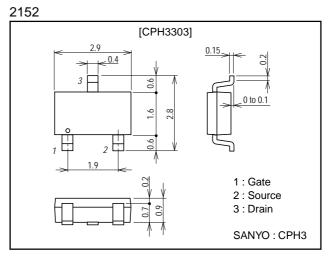
Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	Ι _D		-1.6	A
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	-6.4	A
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² ×0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit	
			min	typ	max	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0	-20			V	
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-20V, V _{GS} =0			-10	μA	
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μA	
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-0.4		-1.4	V	
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-0.8A	1.6	2.4		S	
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	I _D =-0.8A, V _{GS} =-4V		245	315	mΩ	
	R _{DS(on)} 2	I _D =-0.2A, V _{GS} =-2.5V		340	480	mΩ	
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		180		pF	
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		90		pF	
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		43		pF	
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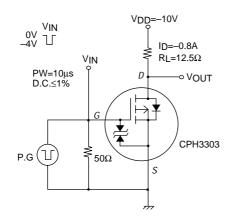
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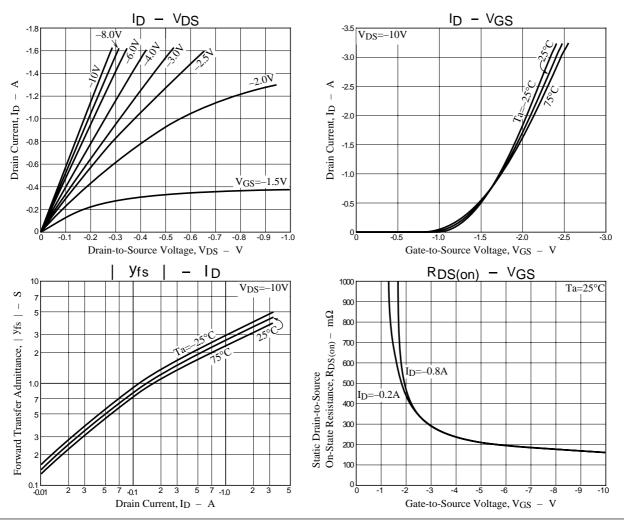
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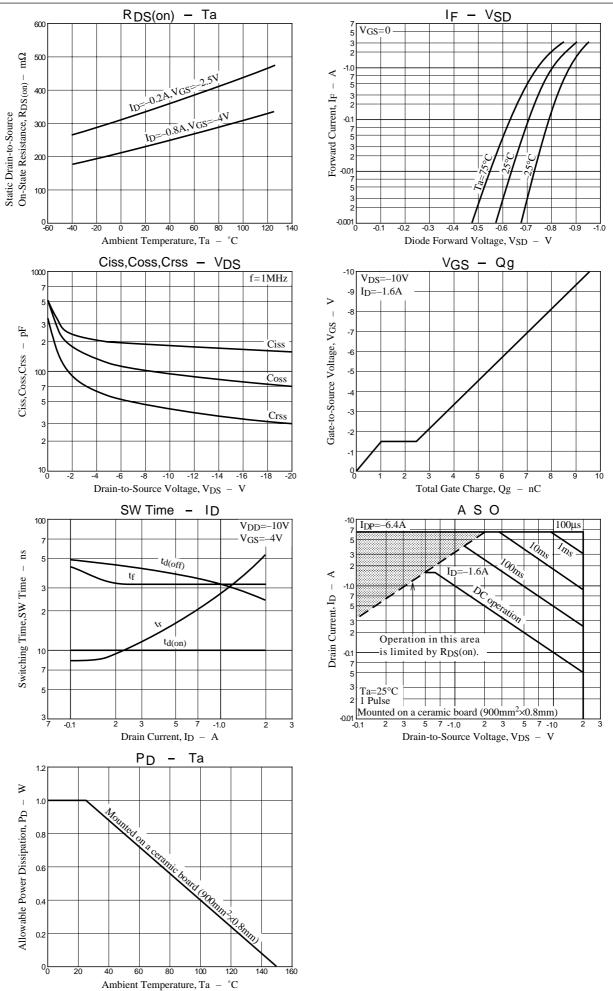
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Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Turn-ON Delay Time	td(on)	See specified Test Circuit		10		ns
Rise Time	tr	See specified Test Circuit		25		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		32		ns
Fall Time	tf	See specified Test Circuit		32		ns
Total Gate Charge	Qg	V _{DS} =-10V, V _{GS} =-10V, I _D =-1.6A		9.5		nC
Gate-to-Source Charge	Qgs	V _{DS} =-10V, V _{GS} =-10V, I _D =-1.6A		1		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-10V, V _{GS} =-10V, I _D =-1.6A		1.5		nC
Diode Forward Voltage	V _{SD}	I _S =-1.6A, V _{GS} =0		-1.0	-1.5	V

Switching Time Test Circuit







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